

# HIGH EFFICIENCY SWITCHED MODE RECTIFIER

#### MAIN PRODUCT CHARACTERISTICS

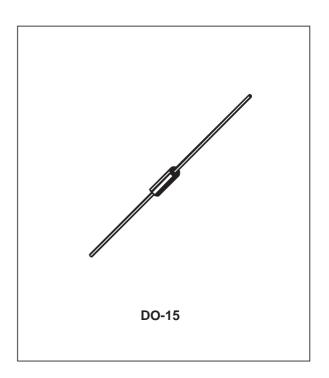
I <sub>F(AV)</sub>	2A
V <sub>RRM</sub>	200V
V <sub>F</sub> (max)	0.8V

### **FEATURES AND BENEFITS**

- VERY LOW CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIMES
- HIGH SURGE CURRENT



Low voltage drop rectifiers suited for Switched Mode Power Supplies and for switching mode base drive and transistor circuit.



# **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit	
$V_{RRM}$	Repetitive peak reverse voltage	200	V	
V <sub>RSM</sub>	Non repetitive peak reverse voltage	220	V	
I <sub>FRM</sub>	Repetive peak forward current	70	Α	
I <sub>F (AV)</sub>	Average forward current * $T_a = 75^{\circ}C$ $\delta = 0.5$		2	А
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 ms$ Sinusoidal		70	А
P <sub>tot</sub>	Power dissipation *	1.85	W	
T <sub>stg</sub> T <sub>j</sub>	Storage temperature range Maximum junction temperature	- 40 to + 150 150	°C	
TL	Maximum lead temperature for soldering 4mm from case	230	°C	

<sup>\*</sup> On infinite heatsink with 10mm lead length

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# **STSR220**

# THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R <sub>th (j - a)</sub>	Junction to ambient thermal resistance *	40	°C/W

<sup>\*</sup> On infinite heatsink with 10mm lead lengh.

# STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub>	Reverse leakage current	$V_R = V_{RRM}$	T <sub>j</sub> = 25°C			10	μΑ
			T <sub>j</sub> = 100°C			0.5	mA
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 2A	T <sub>j</sub> = 25°C			1	V
	drop	I <sub>F</sub> = 2A	T <sub>j</sub> = 100°C			0.8	

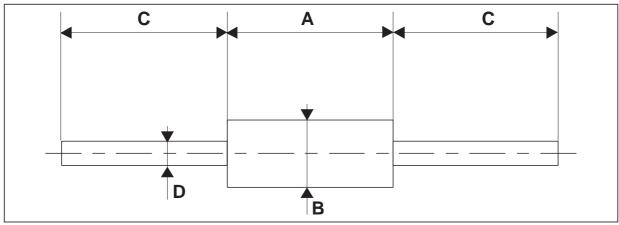
# **RECOVERY CHARACTERISTICS**

Symbol	To	est Conditions		Min.	Тур.	Max.	Unit
t <sub>rr</sub>	$T_j = 25$ °C $V_R = 30$ V	$I_F = 1A$	$di_F/dt = -50A/\mu s$			35	ns
Q <sub>rr</sub>	T <sub>j</sub> = 25°C V <sub>R</sub> < 30V	I <sub>F</sub> = 2A	$di_F/dt = -20A/\mu s$		12		nC
t <sub>fr</sub>	T <sub>j</sub> = 25°C Measured at 1.1x V <sub>F</sub>	I <sub>F</sub> = 1A	t <sub>r</sub> = 10ns		20		ns
V <sub>FP</sub>	T <sub>j</sub> = 25°C	$I_F = 1A$	$t_r = 10$ ns		5		V

To evaluate the conduction losses use the following equation: P = 0.68 x  $I_{F(AV)}$  + 0.06  $I_{F}^{2}_{(RMS)}$ 

# PACKAGE MECHANICAL DATA

DO-15



	DIMENSIONS					
REF.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
А	6.05	6.75	0.238	0.266		
В	2.95	3.53	0.116	0.139		
С	26	31	1.024	1.220		
D	0.71	0.88	0.028	0.035		

Ordering	type	Marking	Package	Weight	Base qty	Delivery mode
STSR2	20	STSR220	DO-15	0.4 g	1000	Ammopack

Cooling method : by convection (method A)

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